



Features

- Excellent dynamic characteristics
- Fast turn-on and high di/dt
- Low switching losses

Typical Applications

- Design for inverter supply application

Part No. Y80KFG-KT75cT

I_{T(AV)}	3354A
V_{DRM}	2000~3000V
V_{RRM}	1000~2500V
t_q	45~100μs

SYMBOL	CHARACTERISTIC	TEST CONDITIONS		T _j (°C)	VALUE			UNIT
					Min	Type	Max	
I _{T(AV)}	Mean on-state current	180° half sine wave 50Hz	T _C =55°C	125			3354	A
V _{DRM}	Repetitive peak off-state voltage	tp=10ms		125	2000		3000	V
V _{RRM}	Repetitive peak reverse voltage				1000		2500	
I _{DRM} I _{RRM}	Repetitive peak current	at V _{DRM} at V _{RRM}		125			250	mA
I _{TSM}	Surge on-state current	10ms half sine wave		125			40	kA
I ² t	I ² t for fusing coordination	V _R =0.6V _{RRM}						8000
V _{TO}	Threshold voltage			125			1.30	V
r _T	On-state slope resistance							0.14
V _{TM}	Peak on-state voltage	I _{TM} =5000A, F=70kN	45μs ≤ t _q ≤ 75μs	25			2.00	V
			76μs ≤ t _q ≤ 100μs				1.80	V
dv/dt	Critical rate of rise of off-state voltage	V _{DM} =0.67V _{DRM}		125			1000	V/μs
di/dt	Critical rate of rise of on-state current (Non-repetitive)	V _{DM} = 67%V _{DRM} , Gate pulse t _r ≤ 0.5μs I _{GM} =1.5A		125			1500	A/μs
Q _{rr}	Recovery charge	I _{TM} =2000A, tp=4000μs, di/dt=-20A/μs, V _R =100V		125		1000		μC
t _q	Circuit commutated turn-off time	I _{TM} =2000A, tp=4000μs, V _R =100V dv/dt=30V/μs, di/dt=-20A/μs		125	45		100	μs
I _{GT}	Gate trigger current	V _A =12V, I _A =1A		25	40		250	mA
V _{GT}	Gate trigger voltage				0.9		2.5	V
I _H	Holding current				20		1000	mA
I _L	Latching current						1500	mA
V _{GD}	Non-trigger gate voltage	V _{DM} =67%V _{DRM}		125			0.3	V
R _{th(j-c)}	Thermal resistance Junction to case	At 180° sine, double side cooled Clamping force 70kN					0.0085	°C /W
R _{th(c-h)}	Thermal resistance case to heatsink						0.0020	
F _m	Mounting force				63		84	kN
T _{vj}	Junction temperature				-40		125	°C
T _{slg}	Stored temperature				-40		140	°C
W _t	Weight					1230		g
Outline	KT75cT							

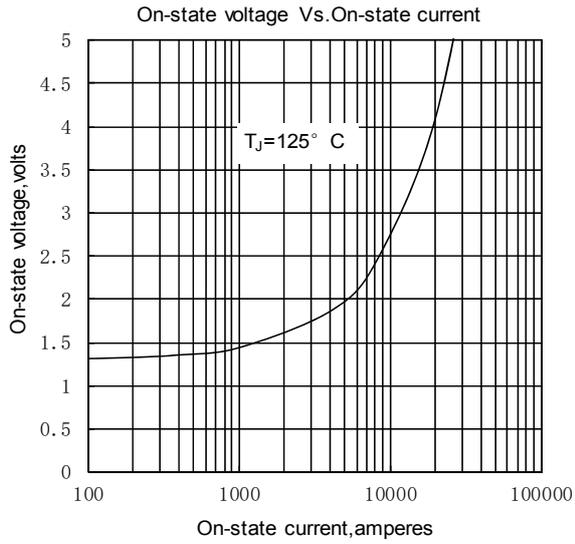


Fig.1

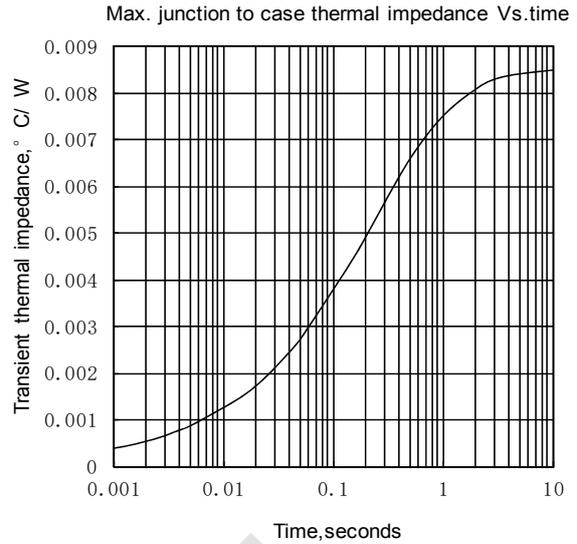


Fig.2

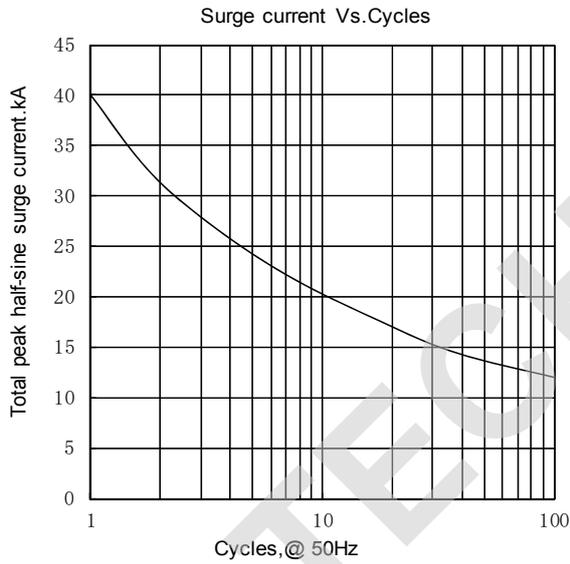


Fig.3

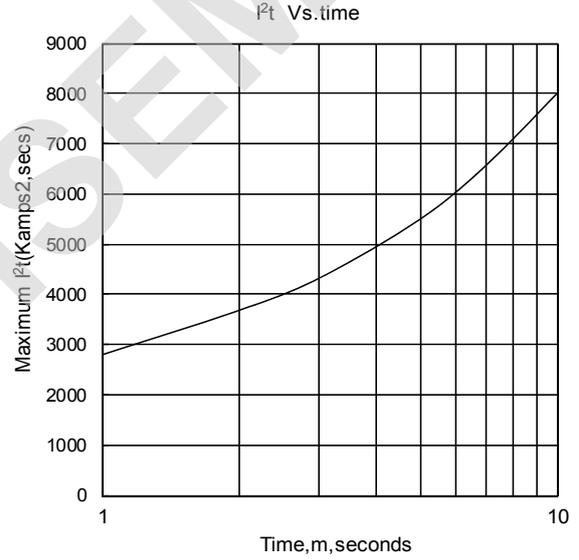


Fig.4

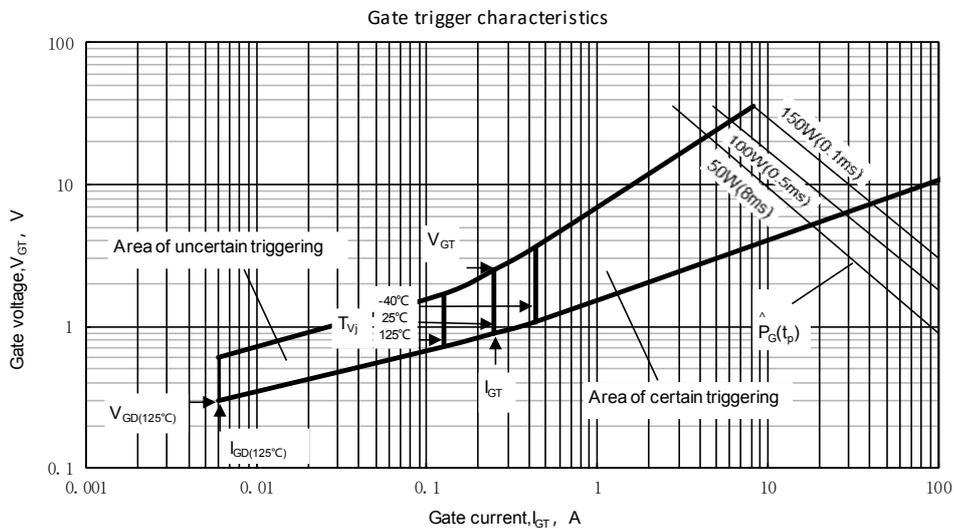
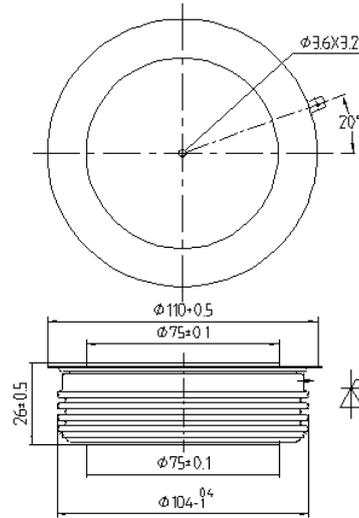


Fig.5

Outline:



TECHSEM reserves the right to change specifications without notice.

TECHSEM